# **ON Semiconductor**

# Is Now



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# **Amplifier Transistors**

#### **Features**

• These are Pb-Free Devices\*

#### **MAXIMUM RATINGS**

| Rating   | Symbol                            | Value       | Unit        |
|--|-----------------------------------|-------------|-------------|
| Collector - Emitter Voltage<br>MPS650; MPS750<br>MPS651; MPS751      | V <sub>CE</sub>                   | 40<br>60    | Vdc         |
| Collector – Base Voltage<br>MPS650; MPS750<br>MPS651; MPS751         | V <sub>CB</sub>                   | 60<br>80    | Vdc         |
| Emitter - Base Voltage   | V <sub>EB</sub>                   | 5.0         | Vdc         |
| Collector Current - Continuous                                       | Ic                                | 2.0         | Adc         |
| Total Power Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 625<br>5.0  | mW<br>mW/°C |
| Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C    | P <sub>D</sub>                    | 1.5<br>12   | W<br>mW/°C  |
| Operating and Storage Junction<br>Temperature Range                  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

# THERMAL CHARACTERISTICS

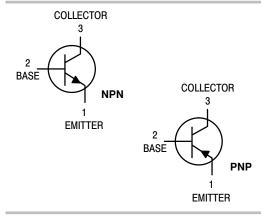
| Characteristic                          | Symbol          | Max  | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction-to-Ambient | V <sub>CE</sub> | 200  | °C/W |
| Thermal Resistance, Junction-to-Case    | V <sub>CB</sub> | 83.3 | °C/W |

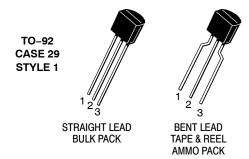
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



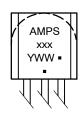
## ON Semiconductor®

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#### **MARKING DIAGRAM**



xxx = 650, 750, 651, or 751 A = Assembly Location

Y = Year WW = Work Week • Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

| Characteristic   |                                  | Symbol                | Min                  | Max              | Unit |
|--|----------------------------------|-----------------------|----------------------|------------------|------|
| OFF CHARACTERISTICS  |                                  |                       |                      |                  |      |
| Collector – Emitter Breakdown Voltage (Note 1) $(I_C = 10 \text{ mAdc}, I_B = 0)$  | MPS650, MPS750<br>MPS651, MPS751 | V <sub>(BR)CEO</sub>  | 40<br>60             | _<br>_           | Vdc  |
| Collector – Base Breakdown Voltage ( $I_C = 100 \mu Adc, I_E = 0$ )  | MPS650, MPS750<br>MPS651, MPS751 | V <sub>(BR)</sub> CBO | 60<br>80             | -<br>-           | Vdc  |
| Emitter – Base Breakdown Voltage ( $I_C = 0$ , $I_E = 10 \mu Adc$ )  |                                  | V <sub>(BR)EBO</sub>  | 5.0                  | _                | Vdc  |
| Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$                                     | MPS650, MPS750<br>MPS651, MPS751 | Ісво                  | -<br>-               | 0.1<br>0.1       | μAdc |
| Emitter Cutoff Current<br>(V <sub>EB</sub> = 4.0 V, I <sub>C</sub> = 0)  |                                  | I <sub>EBO</sub>      | -                    | 0.1              | μAdc |
| ON CHARACTERISTICS (Note 1)  |                                  |                       |                      |                  |      |
| DC Current Gain  |                                  | h <sub>FE</sub>       | 75<br>75<br>75<br>40 | -<br>-<br>-<br>- | -    |
| Collector – Emitter Saturation Voltage ( $I_C = 2.0 \text{ A}, I_B = 200 \text{ mA}$ ) ( $I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$ ) |                                  | V <sub>CE(sat)</sub>  | -<br>-               | 0.5<br>0.3       | Vdc  |
| Base-Emitter On Voltage<br>(I <sub>C</sub> = 1.0 A, V <sub>CE</sub> = 2.0 V)   |                                  | V <sub>BE(on)</sub>   | -                    | 1.0              | Vdc  |
| Base – Emitter Saturation Voltage<br>(I <sub>C</sub> = 1.0 A, I <sub>B</sub> = 100 mA)   |                                  | V <sub>BE(sat)</sub>  | -                    | 1.2              | Vdc  |
| SMALL-SIGNAL CHARACTERISTICS   |                                  |                       | II.                  |                  |      |
| Current – Gain – Bandwidth Product (Note 2)<br>(I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz)                      |                                  | f <sub>T</sub>        | 75                   | _                | MHz  |

- 1. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle = 2.0%.
- 2.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

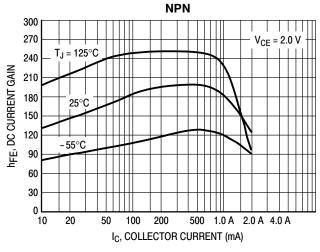


Figure 1. MPS650, MPS651 Typical DC Current Gain

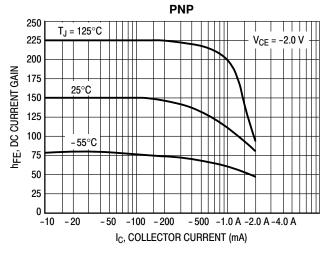


Figure 2. MPS750, MPS751 Typical DC Current Gain

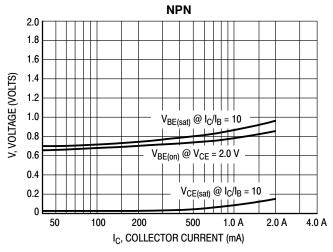


Figure 3. MPS650, MPS651 On Voltages

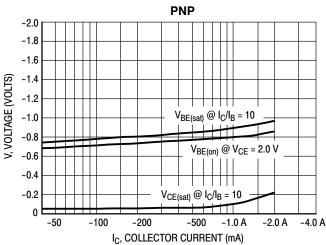


Figure 4. MPS750, MPS751 On Voltages

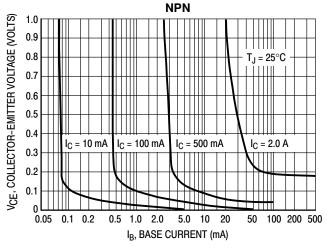


Figure 5. MPS650, MPS651 Collector Saturation Region

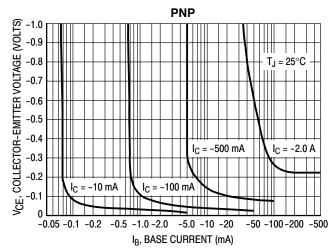


Figure 6. MPS750, MPS751 Collector Saturation Region

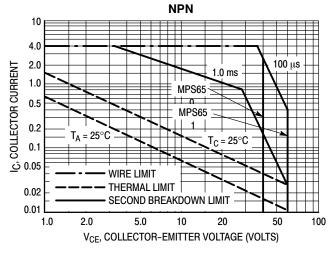


Figure 7. MPS650, MPS651 SOA, Safe Operating Area

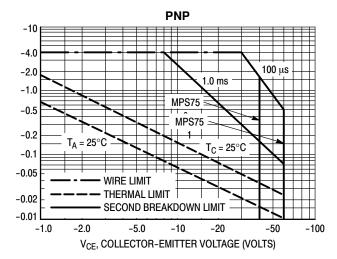


Figure 8. MPS750, MPS751 SOA, Safe Operating Area

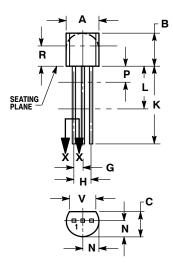
# **ORDERING INFORMATION**

| Device      | Package            | Shipping <sup>†</sup>    |  |
|-------------|--------------------|--------------------------|--|
| MPS650G     | TO-92<br>(Pb-Free) | 5000 Units / Bulk        |  |
| MPS650RLRAG | TO-92<br>(Pb-Free) | 2000 / Tape & Reel       |  |
| MPS650ZL1G  | TO-92<br>(Pb-Free) | 2000 / Tape & Ammunition |  |
| MPS651G     | TO-92<br>(Pb-Free) | 5000 Units / Bulk        |  |
| MPS651RLRAG | TO-92<br>(Pb-Free) | 2000 / Tape & Reel       |  |
| MPS651RLRMG | TO-92<br>(Pb-Free) | 2000 / Tape & Ammunition |  |
| MPS750G     | TO-92<br>(Pb-Free) | 5000 Units / Bulk        |  |
| MPS750RLRAG | TO-92<br>(Pb-Free) | 2000 / Tape & Reel       |  |
| MPS750RLRPG | TO-92<br>(Pb-Free) | 2000 / Tape & Ammunition |  |
| MPS751G     | TO-92<br>(Pb-Free) | 5000 Units / Bulk        |  |
| MPS751RLRAG | TO-92<br>(Pb-Free) | 2000 / Tape & Reel       |  |
| MPS751RLRPG | TO-92<br>(Pb-Free) | 2000 / Tape & Ammunition |  |
| MPS751ZL1G  | TO-92<br>(Pb-Free) | 2000 / Tape & Ammunition |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM

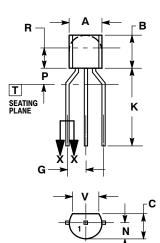


STRAIGHT LEAD **BULK PACK** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| С   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.021 | 0.407  | 0.533  |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| P   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| V   | 0.135  |       | 3.43   |        |



BENT LEAD TAPE & REEL AMMO PACK



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
  CONTOUR OF PACKAGE BEYOND
  DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | MILLIMETERS |      |  |
|-----|-------------|------|--|
| DIM | MIN         | MAX  |  |
| Α   | 4.45        | 5.20 |  |
| В   | 4.32        | 5.33 |  |
| С   | 3.18        | 4.19 |  |
| D   | 0.40        | 0.54 |  |
| G   | 2.40        | 2.80 |  |
| J   | 0.39        | 0.50 |  |
| K   | 12.70       |      |  |
| N   | 2.04        | 2.66 |  |
| P   | 1.50        | 4.00 |  |
| R   | 2.93        |      |  |
| V   | 3.43        |      |  |

PIN 1. EMITTER

BASE

COLLECTOR

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